

Dual Programmable Thyristor Transient Voltage Suppressor

P61089B

General Description

This device has been especially designed to protect 2 new high voltage, as well as classical SLICs, against transient overvoltages.

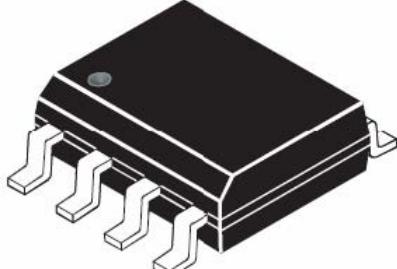
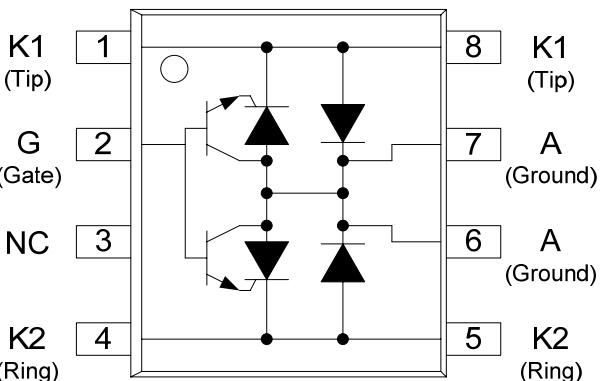
Positive overvoltages are clamped by 2 diodes. Negative surges are suppressed by 2 thyristors, their breakdown voltage being referenced to $-V_{BAT}$ through the gate.

This component presents a very low gate triggering current (I_{GT}) in order to reduce the current consumption on printed circuit board during the firing phase.

This devices are not subject to ageing and provide a fail safe mode in short circuit for a better protection. They are used to help equipment to meet various standards such as UL1950, IEC950/CSA C22.2, UL1459 and FCC part68.

Features

- Dual line programmable transient voltage suppressor
- Wide negative firing voltage range: $V_{MGL} = -155V$
- Holding current: $I_H > 150mA$
- Marking: H61089B
- Low dynamic switching voltages: V_{FP} and V_{DGL}
- Low gate triggering current: $I_{GT} = 5mA$ max
- Halogen Free

Package	Device Symbol
 SOP-8	 K1 (Tip) 1 G (Gate) 2 NC 3 K2 (Ring) 4 8 K1 (Tip) 7 A (Ground) 6 A (Ground) 5 K2 (Ring)

Absolute Maximum Ratings ($T_A=25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Repetitive peak off-state voltage, $V_{GK}=0$	V_{DRM}	-170	V
Repetitive peak gate-cathode voltage, $V_{KA}=0$	V_{GKRM}	-170	V
Non-repetitive peak on-state current 10/1000μs (Telcordia (Bellcore) GR-1089-CORE.Issue 2.February 1999, Section4) 5/320μs (ITU-T K.20, K.21 & K.45, K.44 open-circuit voltage wave shape 10/700μs) 1.2/50μs (Telcordia (Bellcore) GR-1089-CORE.Issue 2.February 1999, Section4) 2/10μs (Telcordia (Bellcore) GR-1089-CORE.Issue 2.February 1999, Section4)	I_{PPSM}	30 40 100 120	A
Non-repetitive peak on-state current. $V_{GG}=-75\text{V}$ 50Hz to 60Hz 0.1s 1s 5s 300s 900s	I_{TSM}	11 4.8 2.7 0.95 0.93	A
Operating free-air temperature range	T_A	-40 to +85	°C
Operating junction temperature range	T_J	-40 to +150	°C
Storage temperature range	T_{STG}	-40 to +150	°C
Lead soldering temperature, 10 seconds	T_{LS}	300(Mix.)	°C

Thermal Characteristics

Parameter	Test Conditions	Max	Unit
$R_{\theta JA}$ Junction to free air thermal temperature	$T_A = 25^\circ\text{C}$, EIA/JESD51-3 PCB, EIA/JESD51-2 environment, $P_{TOT} = 1.7\text{W}$	120	°C/W

Parameter Measurement Information

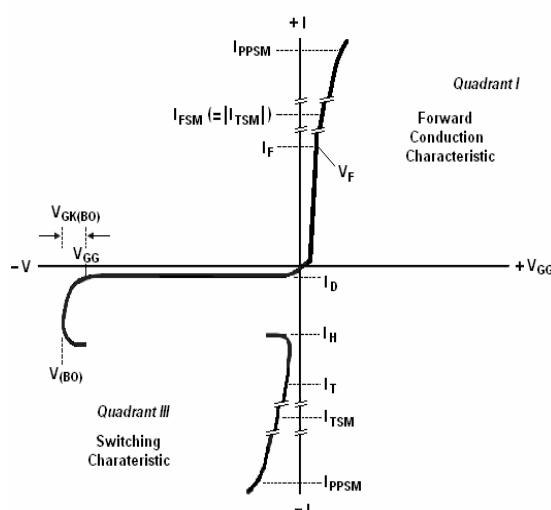


Figure 1. Voltage-Current Characteristic
Unless otherwise noted, all voltages are referenced to the anode

Electrical Characteristics, Rating at 25°C unless otherwise specified

Parameter		Test Conditions	Min.	Typ.	Max.	Unit
I _D	Off-state current	V _D =V _{DRM} , V _{GK} =0, V _{G2} ≥+5V T _J =25°C T _J =85°C			-5 -50	μA
V _(BO)	Breakover voltage	2/10μs, I _{PP} =-56A, R _S =45Ω, V _{GG} =-48V, C _G =220nF 1.2/50μs, I _{PP} =-53A, R _S =47Ω, V _{GG} =-48V, C _G =220nF		-57 -60		V
V _{GK(BO)}	Gate-cathode impulse breakover voltage	2/10μs, I _{PP} =-56A, R _S =45Ω, V _{GG} =-48V, C _G =220nF 1.2/50μs, I _{PP} =-53A, R _S =47Ω, V _{GG} =-48V, C _G =220nF		9 12	20	V
V _F	Forward voltage	I _F =5A, T _W =200μs			3	V
V _{FRM}	Peak forward recovery voltage	2/10μs, I _{PP} =-56A, R _S =45Ω, V _{GG} =-48V, C _G =220nF 1.2/50μs, I _{PP} =-53A, R _S =47Ω, V _{GG} =-48V, C _G =220nF		6 8		V
I _H	Holding current	I _T =-1A, di/dt=1A/ms, V _{GG} =-48V	-150			mA
I _{GKS}	Gate reverse current	V _{GG} =V _{GK} =V _{GKRM} , V _{KA} =0 T _J =25°C T _J =85°C			-5 -50	μA
I _{GT}	Gate trigger current	I _T =-3A, t _{p(g)} ≥20μs, V _{GG} =-48V			5	mA
V _{GT}	Gate-cathode trigger voltage	I _T =-3A, t _{p(g)} ≥20μs, V _{GG} =-48V		2.5	4	V
Q _{GS}	Gate switching charge	1.2/50μs, I _{PP} =-53A, R _S =47Ω, V _{GG} =-48V, C _G =220nF		0.1		μC
C _{KA}	Cathode-anode off- state capacitance	F=1MHz, V _D =1V, I _G =0 V _D =-3V V _D =-48V			100 50	pF

Typical Characteristics

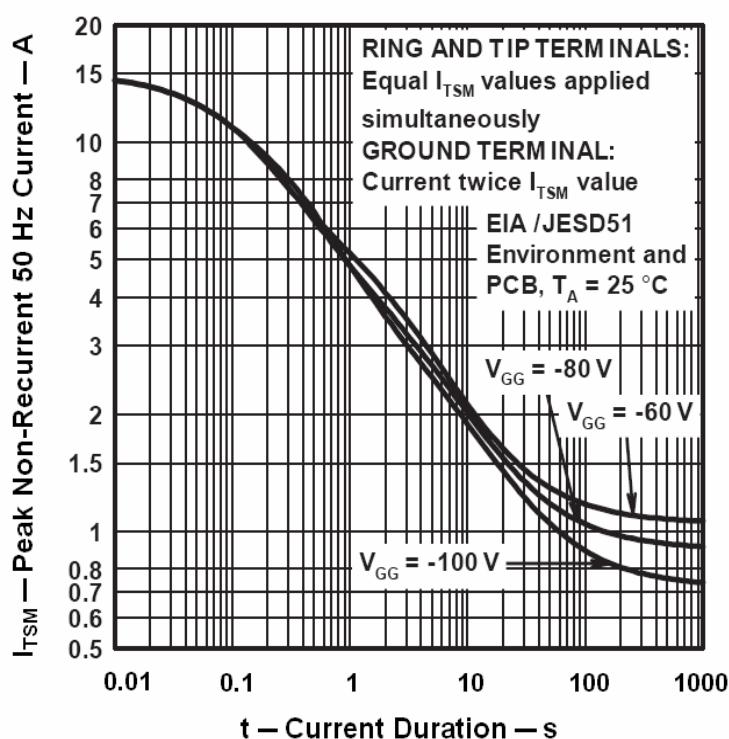
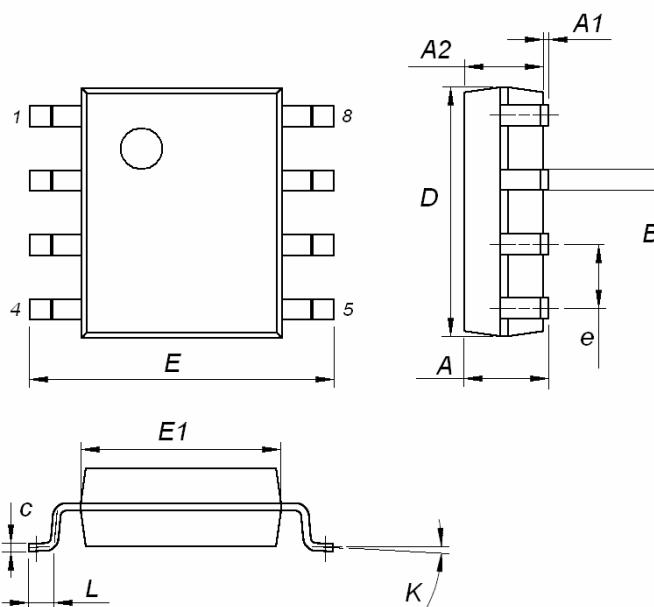


Figure 2. Non-repetitive Peak On-State Current Against Duration

Dimensions (SOP-8)



Symbol	Dimension (mm)		
	Min.	Typ.	Max.
A			1.75
A1	0.10		0.25
A2	1.35	1.55	1.75
B	0.35	0.42	0.49
C	0.19		0.25
D	4.80	4.90	5.00
E	5.80	6.00	6.20
E1	3.80	3.95	4.00
e		1.27	
L	0.40		0.90
K	0°		8°

Tape Package Information

